onsemi

N-Channel General-Purpose Amplifier

MMBFJ201, MMBFJ202

Description

This device is designed primarily for low level audio and general-purpose applications with high impedance signal sources. Sourced from process 52.

Applications

• These are Pb–Free Devices

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$ unless otherwise noted) (Note 1, 2)

Symbol	Parameter	Value	Unit	
V _{DG}	Drain-Gate Voltage	40	V	
V _{GS}	Gate-Source Voltage	-40	V	
I _{GF}	Forward Gate Current	50	mA	
T _J , T _{STG}	Operating and Storage Junction Temperature Range	–55 to 150	°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

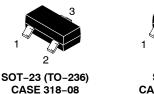
1. These ratings are based on a maximum junction temperature of 150°C.

 These are steady-state limits. onsemi should be consulted on applications involving pulsed or low-duty-cycle operations.

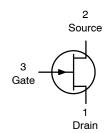
THERMAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted) (Note 3)

Symbol	Parameter	Мах	Unit
P _D Total Device Dissipation		350	mW
	Derate Above 25°C	2.8	mW/°C
$R_{ heta JA}$	Thermal Resistance, Junction-to-Ambient	357	°C/W

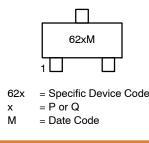
 Device mounted on FR-4 PCB 36 mm x 18 mm x 1.5 mm; mounting pad for the collector lead minimum 6 cm².



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ORDERING INFORMATION

See detailed ordering and shipping information on page 4 of this data sheet.

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Symbol	Parameter	Test Condition	Test Condition		Max	Unit	
OFF CHARACTERISTICS							
V _{(BR)GSS}	Gate-Source Breakdown Voltage	$I_{G} = -1.0 \ \mu A, \ V_{DS} = 0$		-40	-	V	
I _{GSS}	Gate Reverse Current	$V_{GS} = -20 \text{ V}, \text{ V}_{DS} = 0$	$V_{GS} = -20 \text{ V}, \text{ V}_{DS} = 0$		-100	pА	
V _{GS} (off)	Gate-Source Cut-Off Voltage	V _{DS} = 20 V, I _D = 10 nA	MMBFJ201	-0.3	-1.5	V	
			MMBFJ202	-0.8	-4.0		

ON CHARACTERISTICS

I _{DSS}	Zero-Gate Voltage Drain Current (Note 4)	$V_{DS} = 20 \text{ V}, \text{ I}_{GS} = 0$	MMBFJ201	0.2	1.0	mA
			MMBFJ202	0.9	4.5	

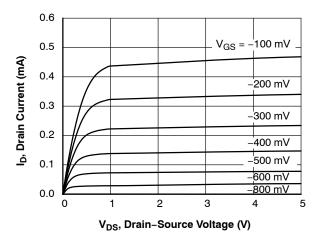
SMALL SIGNAL CHARACTERISTICS

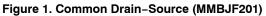
УFS	Forward Transfer Admittance	V _{DS} = 20 V, f = 1.0 kHz	MMBFJ201	500	μmhos
			MMBFJ202	1000	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 4. Pulse test: pulse width $\leq 300 \mu$ s, duty cycle $\leq 2\%$.

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TYPICAL PERFORMANCE CHARACTERISTICS





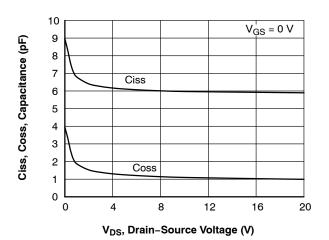


Figure 3. Capacitance vs. Voltage (MMBJF201)

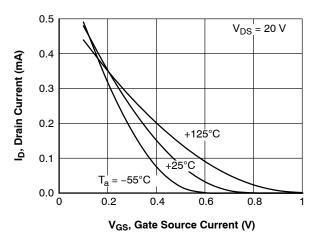


Figure 5. Transfer Characteristics (MMBFJ201)

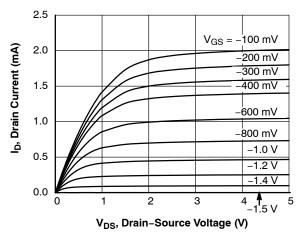


Figure 2. Common Drain-Source (MMBJF202)

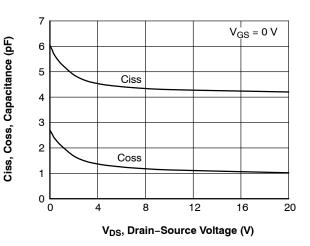
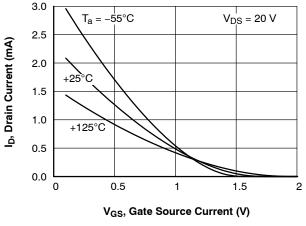


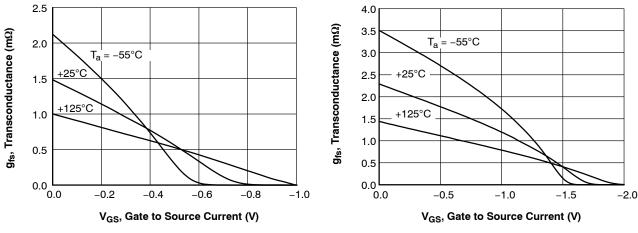
Figure 4. Capacitance vs. Voltage (MMBJF202)





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TYPICAL PERFORMANCE CHARACTERISTICS (continued)







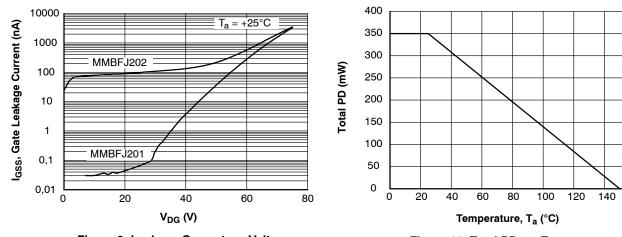


Figure 9. Leakage Current vs. Voltage



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ORDERING INFORMATION

Part Number	Top Mark	Package	Shipping [†]
MMBFJ201	62P	SOT-23 (Pb-Free)	3000 / Tape & Reel
MMBFJ202	62Q	SOT-23 (TO-236) (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D</u>.





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